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RJK0393DPA

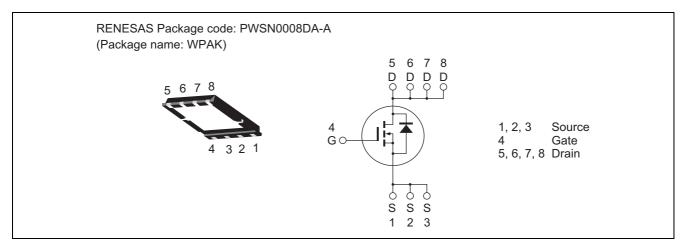
Silicon N Channel Power MOS FET **Power Switching**

> REJ03G1784-0200 Rev.2.00 Apr 03, 2009

Features

- High speed switching
- Capable of 4.5V gate drive
- Low drive current
- High density mounting
- Low on-resistance
 - $R_{DS(on)} = 3.3 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	Ι _D	40	A
Drain peak current	Note1 I _{D(pulse)}	160	A
Body-drain diode reverse drain current	I _{DR}	40	A
Avalanche current	I _{AP} Note 2	16	A
Avalanche energy	E _{AR} Note 2	25.6	mJ
Channel dissipation	Pch Note3	40	W
Channel to case thermal impedance	θch-C	3.13	°C/W
Channel temperature	Tch	150	۵°
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25° C, Rg $\geq 50 \Omega$

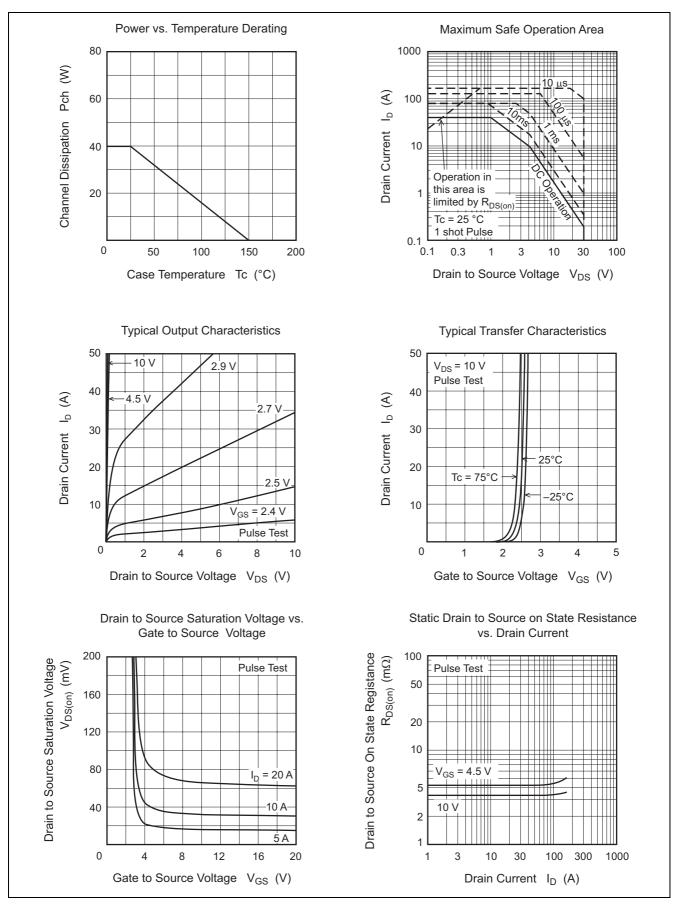
3. Tc = 25°C

Electrical Characteristics

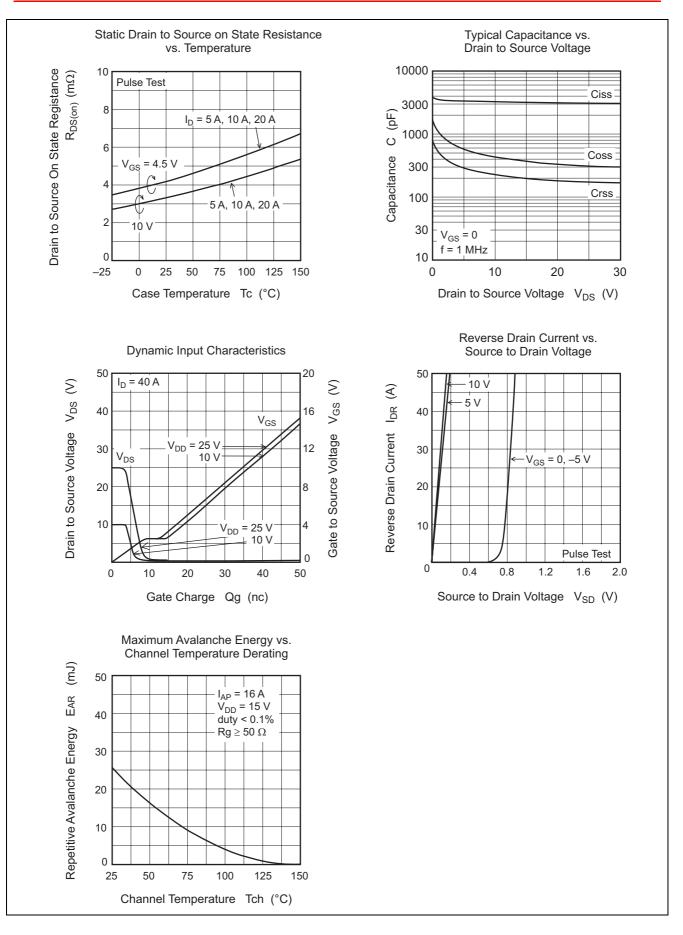
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	—	—	V	$I_{D} = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	—	—	±0.1	μA	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	3.3	4.3	mΩ	$I_D = 20 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	4.2	5.9	mΩ	$I_D = 20 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note4}$
Forward transfer admittance	y _{fs}	_	100	—	S	$I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	3270	—	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$ f = 1 MHz
Output capacitance	Coss	_	430	—	pF	
Reverse transfer capacitance	Crss	_	225	_	pF	
Gate Resistance	Rg		1.4		Ω	
Total gate charge	Qg	_	21	_	nC	$V_{DD} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V},$ $I_D = 40 \text{ A}$
Gate to source charge	Qgs	_	9.5	_	nC	
Gate to drain charge	Qgd	_	4.7	_	nC	
Turn-on delay time	t _{d(on)}	_	13.2	_	ns	
Rise time	tr	_	6.0	_	ns	
Turn-off delay time	t _{d(off)}	_	52	_	ns	
Fall time	t _f		7.1	—	ns	
Body-drain diode forward voltage	V _{DF}	_	0.83	1.08	V	$IF = 40 A, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}	_	23.5	—	ns	IF = 40 A, V _{GS} = 0
time						di _F / dt = 100 A/ μs

Notes: 4. Pulse test

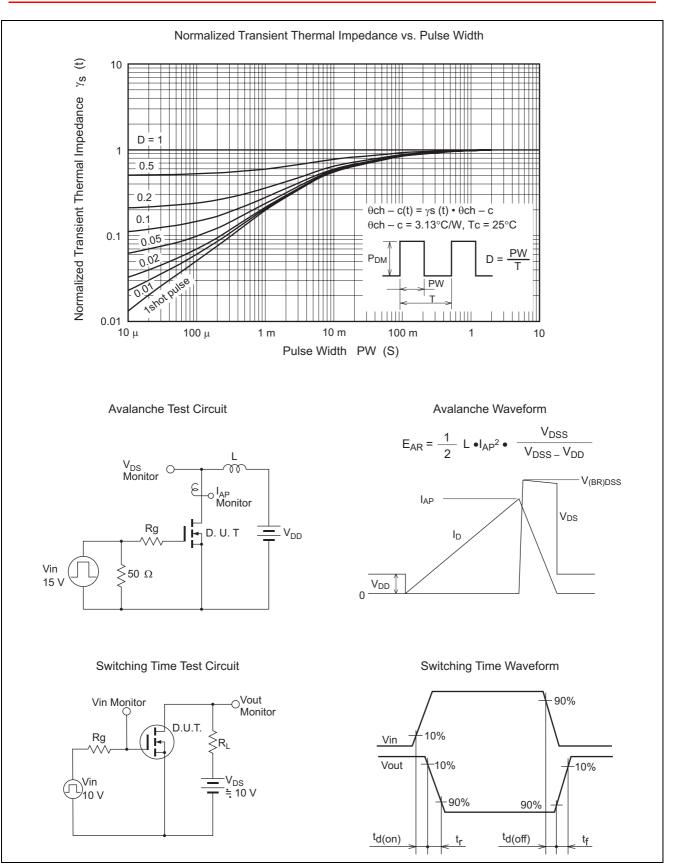
Main Characteristics



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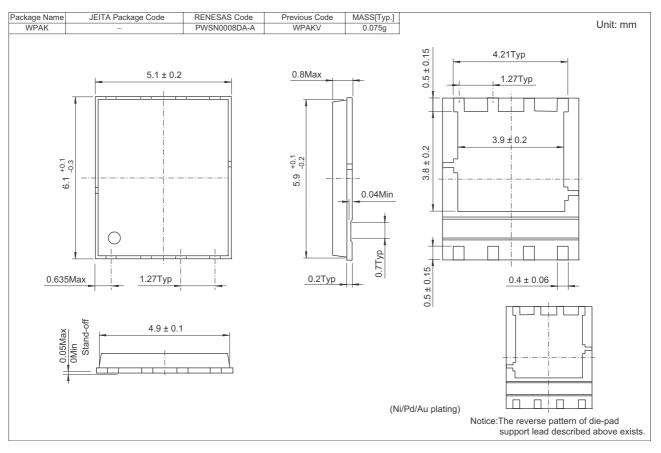


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Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK0393DPA-00-J53	3000 pcs	Taping

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